66'er

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INSTRUCTION MANUAL

Clegg

19,99

INTRODUCTION

UNPACKING

The 66'er has been packed with adequate internal carton bracing and cushioning to withstand normal handling in shipment on common carriers. Examine the carton exterior for signs of severe damage (crushing, piercing, etc.) In the event of obvious serious damage, examine the equipment carefully to determine the extent of internal damage, save packing material and make claim against transportation company.

Check all front panel controls for freedom of action and observe that all tubes and crystals are firmly seated in their sockets. Complete and mail the equipment registration card, to insure validation of warranty.

Many customers have found that saving the shipping carton and the internal cushioning is a great convenience in the event of subsequent need for reshipment or prolonged storage.

GENERAL

The Clegg 66'er has been specifically designed to provide consistent communication on the 6 meter band. This band includes frequencies used by the radio amateur as well as by Military Affiliate Radio Systems, Civilian Defense, and Civil Air Patrol. The 66'er transceiver contains a stable and sensitive receiver and a dependable 22 watt transmitter in one package.

CIVIL DEFENSE Accessories

In addition to the characteristics which make the 66'er outstanding for Civil Defense the following accessories are available for use under all Civil Defense requirements:

Crystal Receive Adapter: Available separately as #800-047, provides crystal receive operation on an assigned C.D. frequency and assures constant on frequency operation.

Special C.D. Case: Utilizes a heavy duty carrying handle, trap door for the crystal rec. adapter and heavy duty feet. #800-805

Transmit Crystal Modification: Allows for exact frequency control of the crystal by the use of a padder capacitor precisely set with your crystals. Tuning Controls: Transmitter controls and shafts can be quickly removed after turning to eliminate accidental mistuning by unauthorized personnel.

In order to familiarize yourself with the 66'er and its many features it is suggested that you read the instruction book completely before attempting to operate your new transceiver.

SPECIFICATIONS

RECEIVER:

- Dual Conversion with 10.7 mhz 1st IF and 456 khz Second IF
- 2. Sensitivity better than $\frac{4}{10}$ uv. for 10 db $\frac{S+N}{N}$
- Selectivity is 8 khz.
- Frequency coverage 49.9 to 52.1 mhz.
 Expanded tuning range available on special order.
- Typical drift is less than 10 khz during warm up and less than 3 khz per hour after 20 minute warmup.
- 6. Rejection of spurious responses down more than 60 db.
- AGC provides more than 10 db compression for 40 db signal increase.

SPECIFICATIONS (Cont'd)

- 8. Squelch threshold adjustable from less than .5 Juv. to more than 500 Juv.
- Switchable ANL provides more than 20 db suppression of typical impulse noise.
- Audio output greater than 2 watts.

TRANSMITTER

- High Efficiency, 22 watts input, 10 watts or more output into 52 ohm load.
- HIGH TALK POWER performance gives high level modulation to 100% with typical -56 db mike.
- 3. Harmonic outputs down more than 50 db.
- Spurious outputs excluding harmonics down more than 66 db.
- Exciter stages are broadband and multituned for quick QSY and low, low spurious (TVI) outputs.
- Built-in Push-To-Talk and provisions to automatically switch the Apollo Linear and/or an external VFO.
- 7. Audio response 300 to 3000 hz. + 3 db.
- Operates with 8.3, 12.5, or 25 mhz. crystals or external VFO.
- Built-in solid state power supply for both 115 volt AC and 12 volt DC operation.

TUBE COMPLIMENT

| 6EH7 | RF Amplifier | 6KE8/2 | Crystal Oscillator multiplier |
|-------|------------------------|--------|-------------------------------|
| 6DJ8 | First Mixer | | to 25 mhz. |
| 6KE8 | Oscillator/Buffer | 6KE8/2 | Doubler to 50 mhz. |
| 6BA6 | 10.7 mhz. IF Amplifier | 12BY7 | Driver (50 mhz.) |
| 6BA6 | Second Mixer | 2E26 | Power Amplifier, Class C |
| 6BA6 | 456 khz. Amplifier | 6AN8 | Two stage Audio Amplifier |
| 12AL5 | Diode Detector/ANL | 2-6AQ5 | Receive Audio/Modulator |
| | 3 semi-conductors | | |

POWER SUPPLY

- Built-in 117 v. ± 5 50-60 cy. supply utilizes power transformer, solid state bridge rectifier and heavy filtering circuits.
- Built-in 13.8 V.D.C. supply with a DC to AC solid state convertor.
- Separate fusing and power connectors for AC and DC operation.
 Power ratings are 50 w. receive and 85 w. transmit nominally.

SIZE AND WEIGHT

12" W. x 12" D. x 6-1/2" H. 19 1bs.

ACCESSORIES

| 66'er Push-to-talk Ceramic Microphone | #551-001 |
|---------------------------------------|----------|
| 66'er Mobile Mount, Adjustable | #800-802 |
| 66'er Crystal Receive Adapter (less | |
| crystal) | #800-047 |
| 66'er C. D. Cabinet (Special Order) | #800-805 |

II. INSTALLATION

A. PRELIMINARY

It is recommended that initial operation of the 66'er be with 117 VAC until the user may familiarize himself with the tune-up and other operating procedures.

The 66'er is supplied with a pre-wired power plug for 117 VAC operation. A Jones plug is supplied for DC operation but this must be wired by you for either positive or negative ground systems. (See Fig. 2, page 5)

B. CRYSTAL INFORMATION

Transmitting crystals are available from your local electronic distributor or by special order from Squires-Sanders, Inc. The following information will be helpful for purchasing your crystals:

Type:

Fundamental Cut HC- U Holder

Except for 25 mc. crystals which are 3 rd overtone

cut.

Frequency:

8,333 khz. to 8,667 khz.

12,500 khz. to 13,000 khz. ± .005%

25,000 khz. to 26,000 khz.

Capacitance:

32 pf. parallel resonant.

C. OPERATION (117 VAC)

117 VAC installations are straightforward. The appropriate power plug is inserted at the rear receptacle and a suitable antenna with less than 2: 1 VSWR is connected to the UHF coax connector. Either the internal speaker or an external 3-8 ohm speaker may be used. In the former case make certain that the short patch cable with phono connectors is in place between the 4 ohm chassis output jack on the rear of the cabinet. (See Fig. 1.)

D. OPERATION (13.8 VDC)

- Wire the 12 volt cord for either negative or positive ground system according to the diagram. (See Fig. 2)
- 2. With either polarity the user must also supply the two primary leads for 13.8 VDC operation. They should be connected to pins 3 and 6. Where the length of the leads between the 66'er and the 13.8 volt source is less than 4 feet, #14 wire can be employed. Should the length exceed 4 feet a heavier gauge wire is recommended.
- Remove the AC fuse.
- Operate your 66'er according to the operation procedures in Section III., P. 7.

E. EXTERNAL V.F.O. INSTALLATION

To operate the 66'er with an external V.F.O., be sure the V.F.O. has an output of 1 to 3 v. rms. at 8.3, 12.5 or 25 mhz. Connect the V.F.O. output to the 66'er crystal socket. The upper socket pin as viewed from the front is the grounded terminal. Keying of the V.F.O. may be accomplished for example, by connecting the keying circuit to 32 of the 66'er, which will ground the circuit on transmit position.

F. EXTERNAL LINEAR AMPLIFIER INSTALLATION

To operate the 66'er with an external linear amplifier simply connect the antenna output of the 66'er to the linear antenna input. Antenna switching must provide bypassing the linear in receive mode. (This is normally provided within the linear.) The 66'er provides approximately 10 watts at 50 ohms output for linear operation. Amplifier switching may be done by utilizing J6 of the 66'er which completes your linear switching circuit to ground.

Or in the law both

66'er SIX METER TRANSCEIVER - REAR VIEW

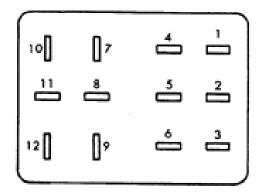
Fig #1

MIC CONNECTIONS

MIC CONNECTIONS

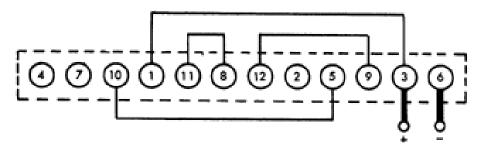
WHO Micro

THE MICRO



DC PLUG PIN LOCATIONS

P1B - FOR 13,8 VDC POS, GND, OPERATION



P1C - FOR 13.8 VDC NEG. GND. OPERATION

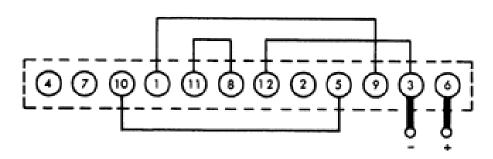


Fig. #2

Fig. #3 66'er FRONT VIEW

L13 and C92 comprise a selective impedance match into the grid of V13 (2E26), which operates as a Class C power amplifier with plate and screen modulation provided through transformer T4. The leakage reactance of T4 and capacitor C102 combine to form an effective low pass splatter filter.

The microphone output is amplified in V7B (6AN8) and further amplified in V7A. On transmit both V8 and V9 are in parallel to furnish the necessary audio power for modulation of the 2E26 stage. Operating levels of the 6AQ5's are such that grid clipping and plate bottoming occur at approximately 10 watts audio level and over modulation is prevented. As noted earlier potential high frequency splatter components are filtered by the design constants of the modulation coupling components.

All transmit-receive switching functions are performed by the four poles of the 12V DC relay, Kl. These functions are:

| K1A | Antenna Transfer |
|-----|------------------|
| В | Modulated B+ |
| C | 250 volts |
| D | Speaker |

In the transmit mode the "D" pole of Kl is employed (in addition to disabling the speaker) to ground auxiliary jack, J6 for control of external devices such as VFO, linear amplifier, external receiver muting, etc.

Kl is normally controlled by the push-to-talk action of a microphone. External and/or remote control of Kl is provided by J3.

C. POWER SUPPLY

The combination power supply furnished with the 66'er operates from 117 \pm 5 volt 60 \pm 5 cps. or 13.8 V \pm .5 VDC.

The unit has a built-in 12 volt DC supply which may be converted to either positive or negative ground systems by properly wiring the DC plug.

A full wave bridge rectifier and filter is employed on both DC and AC operation. Selection of AC or DC is performed automatically by selection of the appropriate plug, PlA, B, or C. DC to DC (12 to 300 volts) voltage inversion is performed by Q1 and Q2 and related circuitry.

Q1 and Q2 are operated at approximately 150 cps. in the common emitter mode to yield a highly efficient inverter.

66'er

2N2869 2N2869

6EH7 6DJ8 6BA6 6BE6 6BA6

6AN8 6AQ5

6AQ5

6KE8 6KE8

12BY 7

2E26

| T U B | TRANSISTOR TUBE ELECTRON | TUBE ELECTRON TUBE ELECTRON | TUBE ELECTRON TUBE ELECTRON | TUBE ELECTRON TUBE ELECTRON | TUBE ELECTRON | | 11 TUBE ELECTRON | 2 TUBE ELECTRON | 3 TUBE ELECTRON |
|-------|-----------------------------|-----------------------------|-----------------------------|-----------------------------|---------------|------|------------------|-----------------|-----------------|
| | | 14 | V 4 V 5 | 12) (13) (51 | | V 10 | V11 | V12 | V13 |
| 1.5 | • | (| $(^{4})$ | <u>ڪ</u>) |) [] | 2 | (| | |
| | |) (| (| 2 1 | |](| | -] | (N 3) |

III. OPERATION

A. RECEIVER SECTION

- Plug in proper Power Connector as shown in Section II and connect 50 ohm 6 meter antenna system to the antenna connector. See p. 4 for locations.
- Advance the RECEIVER AUDIO control from the AC OFF position and allow 1 - 2 minutes for warm up time.
- Turn the SQUELCH control toward full clockwise position.
- Set SPOT-NORMAL-ANL to NORMAL. Procede with tuning of signals.
- After 5-10 minute operation, the S-Meter ZERO ADJUST may be set by adjusting this control on the rear of your 66'er. See p. 4 for location.*
- 6. Insert suitable crystal into the panel crystal holder. See p. 3. Crystal Information: These may be purchased at your local distributor or mail order house. Turn the SPOT-NORMAL-ANL switch to SPOT. The 6 meter frequency of the crystal may now be tuned in on the receiver. To determine the exact frequency multiply the crystal fundamental by 6 (if 8.3 mhz type). For example: 8360 x 6 = 50,160 khz.

 Where ignition or other impulse noise becomes objectionable, such noise may be reduced appreciably by placing the SPOT-NORMAL-ANL switch to the ANL position.

8. The 66'er has a sensitive, stable squelch system. Threshold sensitivity can be varied from less than .5.uv. to several hundred uv. by means of the panel SQUELCH control. Where squelch operation is not desired, this control should be set fully clockwise. Where only strong signals are to operate the squelch system, the SQUELCH control should be set near the lower portion of the range.

The squelch circuit is intentionally of the "leaky" type in which some receiver audio output can always be heard. When a station is received at sufficient strength to activate the squelch, output will inrease from a low level to a suitable comfortable level approximately 20 db louder.

B. TRANSMITTER SECTION

 Install a suitable crystal into the panel crystal socket. Be sure the crystal meets the specifications shown above in Step 6, Receiver Section and Section B. of page 3.

 Connect a high impedance push-to-talk microphone with a properly wired plug into the MIC jack. See the diagram on page 5 for connections. The Squires-Sanders #551-001 microphone is recommended and is available from your local electronics distributor.

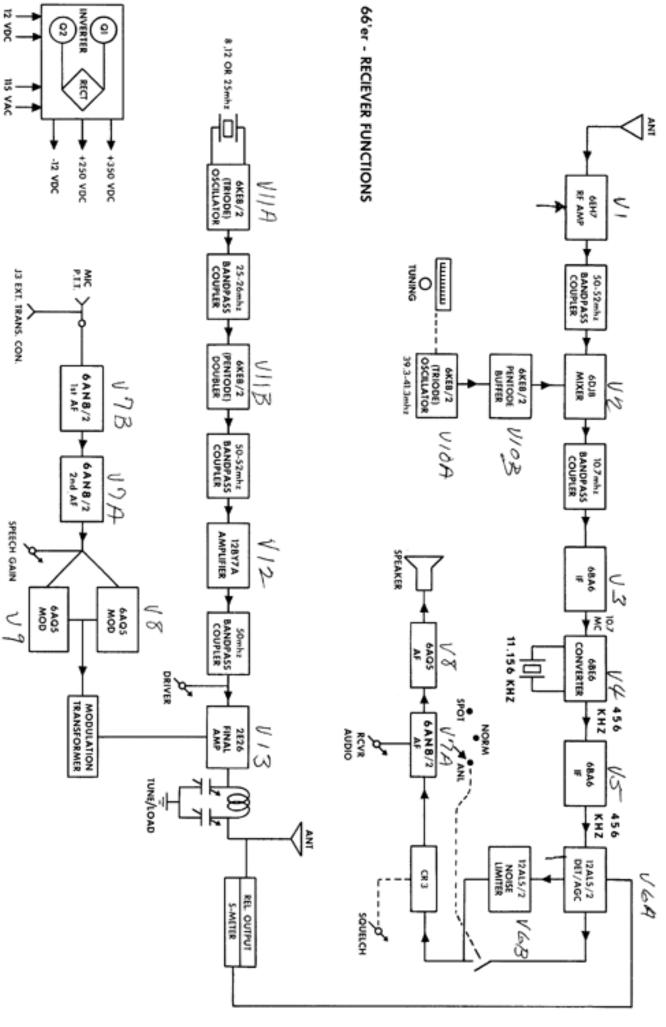
Set the SPEECH GAIN control on rear of chassis to mid range position.
 See page 4 for location.

4. Depress the push-to-talk button on the microphone and adjust the DRIVER, TUNE, and LOAD controls for maximum reading on the S-Meter. The S-Meter will read near midscale with 13 watts or more output if the antenna VSWR is near unity.

Speak into the microphone and advance the SPEECH GAIN control until a slight flicker of the S-Meter is observed. This completes the transmitter tuneup and operation.

* Temporarily remove the antenna for this adjustment.

66'er FUNCTIONAL BLOCK DIAGRAMS



IV. THOERY OF OPERATION

A. RECEIVER

V1 (6EH7) is a high gm pentode operated as low noise RF amplifier with band pass coupling (50 - 52 mhz.) into V2 (6DJ8). V2 is a low-noise first conversion stage to 10.7 mhz. first IF.

Injection at the signal frequency minus 10.7 mhz. is provided by V10 (6KE8) where the triode section is utilized as a stable 39.3 to 41.3 mhz. tunable oscillator and the pentode stage performs as a buffer amplifier.

10.7 mhz. output from V2 is amplified in V3 (6BA6) and converted to 455 Khz. in V4 (6BE6). Self excitation of this conversion is used with the injection frequency at 11.156 Khz. established by the crystal, Y1.

V5 (6BA6) provides amplification at the 455 Khz. second IF frequency.

V6A (1/2 12AL5) functions as a conventional diode AM detector. AGC voltage is generated by this same stage and applied to V3, V4, and V5 directly. AGC is applied to V3, V4, and V5 directly. AGC is applied to V3 parts technique delays application of AGC to V1 until comparatively large input signals exist.

V6B (1/2 12AL5) serves as a series gate impulse noise limiter.

Diode CR 3 functions as a series squelch diode and is arranged to open the audio circuit between the detector output and the first audio stage whenever its cathode is more positive than its anode voltage. Anode voltage is varied automatically by the screen voltage of V5, which inherently follows the AGC level. Cathode voltage (of CR3) is preset to the desired threshold level by means of SQUELCH control, R 41.

Receiver audio gain is controlled by R 44. To prevent the setting of R 44 from influencing audio gain when the 66'er is in the transmit mode, CR 4 is utilized as a diode switch closed in the receive mode only by application of suitable bias via R 45 and R 46.

V7A functions as a conventional audio stage as does V8 (6AQ5) in the receive mode. (R 56, the Transmitter Speech Gain Control is deactivated in the receive mode by diode CR 5 in a manner similiar to that described for CR 4 above.)

B. TRANSMITTER

VIIA (6KE8 triode section) functions as a Colpitts crystal oscillator. Output at crystal harmonics (25 to 26 mhz.) is band pass coupled to VIIB (6KE8 pentode section.) VIIB is a frequency doubler to 50 - 52 mhz. and is also band pass coupled to VI2 (12BY7), the driver stage. Considerable reduction in spurious output is achieved by using straight through operation in the driver stage.

PARTS LIST

| ITEM | DESCRIPTION | NUMBER . | ITEM | DESCRIPTION | PART NUMBER |
|--------------|---|----------|--------------|---|--------------------|
| C1 | CAPACITOR, DISC CERAMIC, 5.6 PF, ± 5%, NPO, 1 KV | 101-109 | C104 | CAPACITOR, ELECTROLYTIC, 50 MFD, 25 V | 107-022 |
| C2 C3 | CAPACITOR, VARIABLE TRIMMER .5-5 FF CAPACITOR, DISC CERAMIC, .0022 MFD +80-20%, 1 KV | 116-001 | C105 C106 | CAPACITOR, DISC CERAMIC, .005 MFD, +80-20%, 150 VAC | 102-077 |
| C4 | CAPACITOR, DISC CERAMIC, .0022 MFD +80-20%, 1 KV | 102-043 | C107 | CAPACITOR, ELECTROLYTIC, 250 MFD, 25 V CAPACITOR, ELECTROLYTIC, 50 MFD, 25 V | 107-011 |
| C5 | CAPACITOR, DISC CERAMIC, 470 PF, ± 10%, 1 KV | 101-003 | C108 | CAPACITOR, ELECTROLYTIC, 50 MFD, 25 V | 107-022 |
| C6 C7 | CAPACITOR, DISC CERAMIC, 6.8 PF, ± 5%, NPO, 1 KV CAPACITOR, DISC CERAMIC, 6.8 PF, ± 5%, NPO, 1 KV | 100-110 | C109 C110 | CAPACITOR, ELECTROLYTIC, 100, 40 MFD @ 450 V, 20 @ 350 V | 108-208 |
| C8 | CAPACITOR, DISC CERAMIC, 20 PF, 2 5%, NPO, 1 KV | 100-110 | C111 | CAPACITOR, ELECTROLYTIC, MFD. 350 V | 107-052 |
| C9 | CAPACITOR, DISC CERAMIC, 10022 MFD +80-20%, 1 KV CAPACITOR, DISC CERAMIC, 0022 MFD +80-20%, 1 KV | 102-043 | C112 | CAPACITOR, DISC CERAMIC, .01 MFD, +80-20%, 500 V | 102-069 |
| C10 C11 | CAPACITOR, DISC CERAMIC, .01 MFD, +80-20%, 500 V CAPACITOR, DISC CERAMIC, 55 PF | 102-069 | C113 | CAPACITOR DISC CERANIC 0022 MPD +80-207 L VV | 102-043 |
| C12 | CAPACITOR, DISC CERAMIC, .0022 MFD, +80-20%, 1 KV | 101-121 | C114 | | |
| C13 | CAPACITOR, DISC CERAMIC, .005 MFD, +80-20%, 500 V | 102-070 | 8118 | DIODE, SILICON, TYPE TISTO | |
| C14 C15 | CAPACITOR, DISC CERANIC, 47 PF, ± 5%, NPO, 1 KV | 100-120 | CRI | Macrosof 1116 1126 | 142-00 |
| C15 | CAPACITOR, VARIABLE TRIMMER, .5-5 PF CAPACITOR, DISC CERAMIC, .01 MFD, +80-20%, 500V | 116-001 | CR2 CR3 | DIODE, GERMANIUM, TYPE IN34 DIODE, SILICON, TYPE TI56 | 141-001 |
| C17 | CAPACITOR, DISC CERANIC, .005 MFD, +80-20%, 500 V | 102-070 | CR4 | DIODE, SILICON, TYPE 1156 | 142-001 |
| C18 C19 | CAPACITOR, DISC CERANIC, .005 MFD, +80-20%, 500 V | 102-070 | CR5 | DICOE, SILICON, TYPE TI56 | 142-001 |
| C20 | CAPACITOR, DISC CERAMIC, .0022 MPD, +80-20%, 1 KV NOT USED | 102-043 | CR6 CR7 | DIODE, SILICON, TYPE SD4 DIODE, SILICON, TYPE SD4 | 142-004 |
| C21 | CAPACITOR, DISC CERAMIC, .005 MFD, +80-20%, 500 V | 102-070 | CR8 | DIODE, SILICON, TYPE SD4 | 142-004 |
| C22 | CAPACITOR, DISC CERANIC, 27 PF, ± 5%, NPO, 1 KV | 100-117 | CR9 | DICOE, SILICON, TYPE SD4 | 142-004 |
| C23 | CAPACITOR, DISC CERANIC, \$70 PF, ±10%, 1 KV CAPACITOR, DISC CERANIC, .005 MFD, +80-20%, 500 V | 101-003 | CR10 CR11 | DIODE, SILICON, TYPE ED3001 | 142-002 |
| C25 | CAPACITOR, DISC CERANIC, .02 MFD, +80-20%, 500 V | 102-056 | CR12 | DIODE, SILICON, TYPE ED3001 DIODE, SILICON, TYPE SD4 | 142-002 142-004 |
| C26 | CAPACITOR, DISC CERAMIC, .02 MFD, +80-20%, 500 V | 102-056 | | 1110 001 | 142 004 |
| C27 C28 | CAPACITOR, DISC CERAMIC, 1 PF, +.25 PF, NPO, 1 KV | 100-100 | | | |
| C29 | CAPACITOR, DISC CERANIC, .005 MFD, +80-20%, 500 V CAPACITOR, DISC CERANIC, .02 MFD, +80-20%, 500 V | 102-070 | P1 | FUSE, 3AG, 15 AMP, 32 VOLTS | 100-025 |
| C30 | POT USED | 100 000 | F2 | FUSE, 3AG, 2 AMP, SLO-BLO, 125 V | 165-020 |
| C31 C32 | CAPACITOR, DISC CERAMIC, 470 PF, ±10%, 1 KV | 101-003 | | | |
| 032 | CAPACITOR, DISC CERANIC, .02 MFD, +80-20%, 500 V CAPACITOR, DISC CERANIC, .02 MFD, +80-20%, 500 V | 102-056 | | | |
| C34 | CAPACITOR, DISC CERAMIC, 470 PF, ± 10%, 1 KV | 101-003 | 11 | LAMP, INCANDESENT, FROSTED, #1847 | 150-101 |
| 035 | CAPACITOR, DISC CERAMIC, 470 PF, ± 10%, 1 KV | 101-003 | 12 | LAMP, INCANDESENT, PROSTED, #1847 | 150-101 |
| C36 C37 | CAPACITOR, DISC CERAMIC, .02 MFD, +80-20%, 500 V CAPACITOR, DISC CERAMIC, .0022 MFD, +80-20%, 1 KV | 102-056 | 1 1 | | |
| C38 | CAPACITOR, DISC CERANTC, .0022 MFD, +80-20%, 1 KV | 102-043 | J1 | PLUC, 12 PIN CHASSIS MOUNT | 292-020 |
| C39 | CAPACITOR, DISC CERAMIC, 470 PF, ± 10%, 1 KV | 101-003 | J2 | CONNECTOR, UHF | 291-101 |
| C40 C41 | NOT USED | | 13 | PHONE JACK, 1 PIN | 293-003 |
| C42 | CAPACITOR, MYLAR, .1 MFD, ± 10%, 400 V CAPACITOR, DISC CERANIC, .05 MFD, ± 10%, 1 KV | 105-304 | J4 J5 | PHONE JACK, 1 PIN PHONE JACK, 1 PIN | 293-003 |
| C43 | CAPACITOR, DISC CERAMIC, .0022 MFD, +80-20%, 1 KV | 102-043 | J5 | PHONE JACK, 1 PIN | 293-003 |
| C44 C45 | CAPACITOR, DISC CERANIC, .0022 MFD, +80-20%, 1 KV | 102-043 | 37 | PHONE JACK, MIC | 293-00b |
| C46 | CAPACITOR, DISC CERAMIC, .02 MFD, +80-20%, 500 V CAPACITOR, DISC CERAMIC, 22 PF, ±5%, MPO, 1 KV | 102-056 | | | |
| C47 | CAPACITOR, DISC CERAMIC, .05 MFD, # 10%, 1 KV | 102-059 | К1 | RELAY, 4 PDT, 12 VDC | 174-002 |
| C48 | CAPACITOR, DISC CERAMIC, .01 MFD, +80-20%, 500 V | 102-069 | | , | |
| C49 C50 | CAPACITOR, DISC CERAMIC, .02 MFD, +80-20%, 500 V NOT USED | 102-056 | Ll | COIL, SLUC TUNNED 0.5 - 1.0 Auh | 182-007 |
| C51 | CAPACITOR, DISC CERAMIC, 5.4 MFD @ 5.4 V | 107-025 | L2 L3 | COIL, SLUG TUNNED 0.5 - 1.0 µh COIL, SLUG TUNNED 0.5 - 1.0 µh | 182-007 |
| C52 | CAPACITOR, DISC CERAMIC, .02 MFD, +80-20%, 500 V | 102-056 | L4 | COIL, SLUC TUNNED 7-18 July / 10-1/2 T Sec. | 182-034 |
| C53 C54 | CAPACITOR, DISC CERAMIC, .05 MFD, ± 10%, 1 KV CAPACITOR, ELECTROLYTIC, 10 MFD @ 25 V | 102-059 | L5 | COIL, SLUG TUNNED 2.57 - 6.3 Juh | 182-034 |
| C55 | CAPACITOR, DISC CERANIC, .01 MFD, +80-20%, 500 V | 102-069 | L5 L7 | COIL, CHOKE, RF, 120 ah COIL, CHOKE, 20 T, #26 WOUND ON 6.8K, 1 W, RESISTOR | 190-008 |
| C56 | CAPACITOR, ELECTROLYTIC, 10 MFD, @ 25 V | 107-019 | E.8 | COIL, SLUC TUNED, 0.43 - 0.70 uh | 182-030 |
| C57 C58 | CAPACITOR, ELECTROLYTIC, 10 MFD @ 25 V | 107-019 | L9 | COIL, SLUC TUNED, 1.7 - 4.0h | 182-015 |
| 059 | CAPACITOR, DISC CERAMIC, .005 MFD, +80-20%, 500 V CAPACITOR, DISC CERAMIC, .0022 MFD, +80-20%, 1 EV | 102-070 | L10 | COIL, SLUC TUNED, 1.7 - 4 Ah COIL, SLUG TUNED, .3672 Ah/1-1/2 T SEC. | 182-015 |
| C60 | NOT USED | | 5,12 | COIL, SLUC TUNED, .3672 uh/1-1/2 T SEC. | 182-020 |
| C61 C62 | CAPACITOR, AIR-VARIABLE, 6.8-20 PF | 110-026 | 5.13 | COIL, CHOKE, RF, 7 uh | 190-002 |
| C63 | CAPACITOR, SILVER MICA, 110 PF, ± 5% CAPACITOR, SILVER MICA, 39 PF, ± 5% | 103-117 | L14 | COIL, 11 TURNS, 16TPI, 5/8" DIA. COIL, CHOKE, RF, 7_oh INSULATED | 191-010 |
| C64 | CAPACITOR, TUBULAR CERAMIC, 10 PF, ± 5%, N750 | 105-030 | Llő | COIL, 4 TURNS, 8 TPI, 1-1/4 DIA. | 191-055 |
| C65 | CAPACITOR, SILVER MICA, 240 PF, ± 2% | 103-138 | 1 | | |
| C67 | CAPACITOR, SILVER MICA, 110 PF, ± 5% CAPACITOR, DISC CERAMIC, 27 PF, ± 5%, NPO, 1 KV | 103-117 | | | |
| C68 | NOT USED | 1 | М1 | METER "S" SCALE, 0-1 MA | 409-004 |
| C69 | CAPACITOR, DISC CERAMIC, .005 MFD, +80-20%, 500 V | 102-070 | | | |
| C70 C71 | NOT USED CAPACITOR, DISC CERANIC, 470 PF, ± 10%, 1 KV | 101-003 | 01 | TOLINGTON DAMES ANDRESS AND | |
| C72 | CAPACITOR, DISC CERAMIC, .02 MFD, +80-20%, 500 V | 102-056 | Q1 Q2 | TRANSISTOR, FOWER, 2N2869 RGA TRANSISTOR, FOWER, 2N2869 RGA | 200-019 |
| C73 | CAPACITOR, DISC CERAMIC, .005 MFD, +80-20%, 500 V | 102-070 | " | Transcoron, comme, anevy men | 200-019 |
| C74 C75 | CAPACITOR, DISC CERAMIC, .02 MFD, +80-20%, 500 V | 102-056 | ., | | |
| C76 | CAPACITOR, DIPPED MICA, 18 PP, ± 5%, 500 V CAPACITOR, DISC CERAMIC, 10 PF, ± 5%, NPO, 1 KV | 104-103 | R1 R2 | RESISTOR, COMP., 330 K, ± 10Z, 1/2 W. RESISTOR, COMP., 270 OHMS, ± 10Z, L/2 W. | 223-334 |
| C77 | CAPACITOR, DISC CERAMIC, 27 PF, ± 5%, NPO, 1 KV | 100-117 | R3 | RESISTOR, COMP., 33 K, ± 10%, 1 W. | 225-333 |
| C78 | CAPACITOR, DISC CERAMIC, 68 PF, ± 5%, NPO, 1 KV | 100-122 | R4 | RESISTOR, COMP., 1.2 K, ± 10%, 1/2 W. | 223-122 |
| C79 C80 | CAPACITOR, DISC CERAMIC, .0022 MFD, +80-20%, 1 KV NOT USED | 102-043 | R5 | RESISTOR, COMP., 220 K, ± 10%, 1/2 W. | 223-224 |
| C81 | CAPACITOR GIMMICK | | R6 R7 | RESISTOR, COMP., 680 OHMS. + 10%, 1/2 W. RESISTOR, COMP., 10 K. ± 10%, 1/2 W. | 223-581 223-103 |
| C82 | CAPACITOR, DISC CERAMIC, 6.8 PF, ±.25%, NPO, 1 KV | 100-110 | R8 | RESISTOR, COMP., 27 OHMS, ± 10%, L/2 W. | 223-270 |
| C83 C84 | CAPACITOR, DISC CERANIC, .0022 MFD, +80-20%, 1 KV | 102-043 | R9 | RESISTOR, COMP., 2.2 K, ± 10%, 1/2W | 223-222 |
| C85 | CAPACITOR, DISC CERAMIC, .0022 MFD, +80-20%, 1 KV CAPACITOR, DISC CERAMIC, 10 PF, ± 5%, MPO, 1 KV | 102-043 | R10 | RESISTOR, COMP., 33 K, ± 10%, 1 W. RESISTOR, COMP., 18 K, ± 10%, 2 W | 225-333 |
| C86 | CAPACITOR, DISC CERAMIC, .0022, +80-20%, 1 KV | 102-043 | R1.2 | RESISTOR, COMP., 220 K, ± 10%, 1/2 W. | 223-224 |
| C87 | CAPACITOR, DISC CERAMIC, 6.8 PF, ±.25 PF, MPC, 1 XV | 100-110 | R13 | RESISTOR, COMP., 150 OMMS, ± 10%, 1/2 W | 223-151 |
| C88 C89 | CAPACITOR, DISC CERAMIC, 470 FF, ± 107, 1 KV CAPACITOR, DISC CERAMIC, .0022 MPD, +80-207, 1 KV | 101-003 | R14 R15 | RESISTOR, COMP., 33 K, ± 10%, 1/2 W RESISTOR, COMP., 1.8 K, ± 10%, 1/2 W | 223-333 223-182 |
| C90 | CAPACITOR, DISC CERAMIC, 470 PF. ± 10%, 1 KV | 101-003 | R16 | RESISTOR, COMP., 1.8 K, 7 10%, 1/2 W RESISTOR, COMP., 220 K, ± 10%, 1/2 W | 223-182 |
| C91 | CAPACITOR, DISC CERAMIC, 470 PF, ± 10Z, 1 KV | 101-003 | R17 | RESISTOR, COMP., 560 OHMS, ± 10%, 1/2 W | 223-561 |
| C92 C93 | CAPACITOR, AIR VARIABLE, 2-7 PF CAPACITOR DISC CERAMIC 68 PF + 57 MPO 1 MV | 110-024 | R18 R19 | RESISTOR, COMP., 47 K, ± 10%, 1/2 W | 223-473 |
| C94 | CAPACITOR, DISC CERAMIC, 68 PF, ± 57, NPO, 1 KV CAPACITOR, DISC CERAMIC, 2.2 PF, ± .25 PF, NPO, 1 KV | 100-122 | R19 R20 | RESISTOR, COMP., 12 K, ± 10%, 1 W RESISTOR, COMP., 47 OHMS, ± 10%, 1/2 W | 225-123 |
| C95 | CAPACITOR, GIMMICK | | R21 | RESISTOR, COMP., 1.8 K, ± 10%, 1/2 W | 223-470 |
| C96 | CAPACITOR, DISC CERAMIC, 470 PF, ± 10%, 1 KV | 101-003 | R22 | RESISTOR, COMP., 220 K, ± 10%, 1/2 W | 223-224 |
| C97 C98 | CAPACITOR, DISC CERAMIC, 470 PF, ± 10%, 1 KV CAPACITOR, SILVER MICA, 300 PF, 2%, 1500 V | 101-003 | R23 R24 | RESISTOR, COMP., 1 K, ± 10%, 1/2 W | 223-102 |
| C99 | CAPACITOR, AIR VARIABLE, 3-10 PF | 110-025 | R25 | RESISTOR, VARIABLE M/SWITCH 5 K RESISTOR, COMP., 3.3 K, ± 10%, 1 W | 241-005 225-332 |
| C100 | CAPACITOR, DISC CERAMIC, .02 MFD, ± 80-20%, 500 V | 102-056 | R26 | RESISTOR, COMP., 6.8 K, ± 10%, 1/2 W | 223-682 |
| C101 C102 | CAPACITOR, VARIABLE, 6.2 to 142 PF CAPACITOR, DISC CERAMIC, .005 MPD, ±80-20%, 500 V | 110-030 | R27 | RESISTOR, COMP., 680 K, ± 10%, 1/2 W | 223-684 |
| C102 | CAPACITOR, ELECTROLYTIC, 50 MFD, 25 V | 102-070 | R28 R29 | RESISTOR, COMP., 3.9 K, ± 10%, 1/2 W RESISTOR, COMP., 220 ORMS, ± 10%, 1/2 W | 223-392 223-221 |
| | | | ^**/ | | 223-221 |
| 1 | | I | | 1 | í |

PARTS LIST (Cont'd.)

| ITEM | DESCRIPTION | PART NUMBER | | ITEM | DESCRIPTION | PART NUMBER | | | | | | | | | | | |
|--|--|--|--|---|---|---|------|---|--|--|--|--|--|--|--|--|--|
| R30 R31 R32 R33 R34 R35 R36 R37 R38 R39 R40 R41 R42 R43 R44 R45 R47 R48 R60 R51 R52 R62 R63 R56 R57 R56 R57 R58 R59 R61 R62 R63 R64 R65 R67 R67 R68 R67 R68 R67 R68 R67 R68 R67 R68 R67 R68 R68 R69 R69 R69 R69 R69 R69 R69 R69 R69 R69 | RESISTOR, COMP., 100 K, ± 10%, 1/2 W RESISTOR, COMP., 1 MEG, ± 10%, 1/2 W RESISTOR, COMP., 23 K, ± 10%, 1/2 W RESISTOR, COMP., 47 K, ± 10%, 1/2 W RESISTOR, COMP., 47 K, ± 10%, 1/2 W RESISTOR, COMP., 220 K, ± 10%, 1/2 W RESISTOR, COMP., 120 MC, ± 10%, 1/2 W RESISTOR, COMP., 470 K, ± 10%, 1/2 W RESISTOR, COMP., 120 K, ± 10%, 1/2 W RESISTOR, COMP., 120 K, ± 10%, 1/2 W RESISTOR, COMP., 12 MEG, ± 10%, 1/2 W RESISTOR, COMP., 120 MG, ± 10%, 1/2 W RESISTOR, COMP., 10%, 10%, 10%, 1/2 W RESISTOR, COMP., 220 K, ± 10%, 1/2 W RESISTOR, COMP., 230 MC, ± 10%, 1/2 W RESISTOR, COMP., 33 MC, ± 10%, 1/2 W RESISTOR, COMP., 270 K, ± 10%, 1/2 W RESISTOR, COMP., 470 K, ± 10%, 1/2 W RESISTOR, COMP., 33 MEG, ± 10%, 1/2 W RESISTOR, COMP., 39 MG, ± 10%, 1/2 W RESISTOR, COMP., 39 MG, ± 10%, 1/2 W RESISTOR, COMP., 470 K, ± 10%, 1/2 W RESISTOR, COMP., 470 K, ± 10%, 1/2 W RESISTOR, COMP., 10 K, ± 10%, 1/2 W RESISTOR, COMP., 12 K, ± 10%, 1/2 W RESISTOR, COMP., | | | | CHASSIS CHASSIS, LOW PASS FILTER DIAL PLATE, PLASTIC DUST COVER FRONT PANEL SPEAKER BALL DRIVE BUMPER, SMALL BUMPER, LARGE CAP, PLATE CABLE, JUMPER ASSEMBLY (SHIELDED CABLE 6" & PLUGS) CORD, DIAL-NYLON COUFLER, SHAFT FUSE HOLDER GROMMET, 1/4 I.D. KNOB, CONTROL, LARGE KNOB, TUNING, SMALL LAMPHOLDER, DIAL CABLE ASSEMBLY, A.C. POWER POINTER, DIAL LLOWING CHANGES AND ADDITIONS SHOULD BE READ INTO THE ABOVE CHANGES CAPACITOR, DISC CERAMIC, .01 MFD, +80-20%, 500 V. CAPACITOR, DISC CERAMIC, .02 MFD, +80-20%, 500 V. CAPACITOR, DISC CERAMIC, .02 MFD, +80-20%, 500 V. CAPACITOR, DISC CERAMIC, .12 WFD, 1/2 W RESISTOR, COMP., 470 K, ±10%, 1/2 W RESISTOR, COMP., 1 K, ± 10%, 1/2 W. RESISTOR, COMP., 1 K, ± 10%, 1/2 W. RESISTOR, COMP., 100 K, ± 10%, 1/2 W. TUBE, ELECTRON, TYPE 6ANB CRYSTAL, 11.156 mhz. | 341-014 341-017 339-020 (56 342-026 340-009 (66 550-001 328-039M 332-016 320-502 510-017 338-007 328-058 300-001 332-003 330-323 330-323 330-323 330-323 | 'er) | | | | | | | | | | |
| R69 R70 | RESISTOR, COMP., 150 OHMS, ± 10%, 1/2 W RESISTOR, COMP., 1.2 MEG., ± 10%, 1/2 W | 223-151 223-125 | / | THE FO | | PARTS LIST. | | | | | | | | | | | |
| R71 R72 R73 R74 R75 R76 R77 R78 R80 R81 R82 R83 R84 R85 R86 R90 R91 R92 R93 R94 R95 R96 R97 R96 R97 R97 R97 R97 R97 R97 R97 R97 R97 R97 | RESISTOR, COMP., 10 K, ± 10%, 1 W RESISTOR, COMP., 6.8 K, ± 10%, 1/2 W RESISTOR, COMP., 39 K, ± 10%, 1/2 W RESISTOR, COMP., 39 K, ± 10%, 2 W RESISTOR, COMP., 10 K, ± 10%, 1/2 W RESISTOR, COMP., 1.2 K, ± 10%, 1/2 W RESISTOR, COMP., 1.2 K, ± 10%, 1/2 W RESISTOR, COMP., 56 K, ± 10%, 1/2 W RESISTOR, COMP., 39 K, ± 10%, 1/2 W RESISTOR, COMP., 1.2 K, ± 10%, 1/2 W RESISTOR, COMP., 1.2 K, ± 10%, 1/2 W RESISTOR, COMP., 1.2 K, ± 10%, 1/2 W RESISTOR, COMP., 18 K, ± 10%, 1/2 W RESISTOR, COMP., 18 K, ± 10%, 1/2 W RESISTOR, COMP., 18 K, ± 10%, 1/2 W RESISTOR, COMP., 12 OHMS, ± 10%, 1/2 W RESISTOR, COMP., 12 K, ± 10%, 1/2 W RESISTOR, COMP., 8.2 OHMS, ± 5%, 1/2 W RESISTOR, W. W., 150 OHMS, 5 W RESISTOR, W. W., 150 OHMS, 5 W RESISTOR, W. W., 150 OHMS, 5 W RESISTOR, COMP., 8.2 OHMS, ± 5%, 1/2 W RESISTOR, COMP., 8.2 OHMS, ± 5%, 1/2 W RESISTOR, W. W., 75 OHMS, 5 W RESISTOR, COMP., 8.2 OHMS, ± 10%, 1/2 W RESISTOR, COMP., 12 K, ± 10%, 1/2 W RESISTOR, COMP., 12 C, ± 10%, 1/2 W RESISTOR, COMP., 12 C, ± 10%, 1/2 W RESISTOR, COMP., 12 C, ± 10%, 1/2 W RESISTOR, COMP., 100 OHMS, ± 10%, 1/2 W | 223-151 223-125 223-125 225-103 225-682 223-393 227-223 223-103 223-122 223-563 223-393 223-122 243 | 225-682 223-393 227-223 223-103 223-122 223-563 223-393 223-122 223-184 223-220 227-183 223-80 225-124 223-123 225-273 223-820 225-273 223-820 223-206 222-082 232-006 232-006 232-006 222-082 233-007 223-121 223-121 | 151 125 103 682 393 223 103 122 563 393 122 563 393 122 122 184 122 188 124 123 124 123 124 127 128 129 120 124 120 124 127 127 128 129 129 120 120 120 120 120 120 120 120 | 25 82 83 82 83 22 23 303 22 23 393 22 24 220 83 200 224 223 224 224 223 220 200 200 200 200 200 200 | 3 | 3 | , | | | | | | C55 C68 CR1 R31 R35 R43 R106 | CAPACITOR, DISC CERAMIC, .01 MFD, +80-20%, 500 V. CAPACITOR, DISC CERAMIC, .02 MFD, +80-20%, 500 V. CAPACITOR, DISC CERAMIC, 3.3 PF, ± 5% DIODE, SILICON, TYPE T156 RESISTOR, COMP., 470 K, ±10%, 1/2 W. RESISTOR, COMP., 1 K, ± 10%, 1/2 W. RESISTOR, COMP., 100 K, ± 10%, 1/2 W. RESISTOR, COMP., 470 K, ± 10%, 1/2 W. TUBE, ELECTRON, TYPE 6AN8 | 102-056 100-106 142-001 223-474 223-102 223-104 223-474 216-005 | |
| \$1 \$2 | PART OF R44 ROTORY, 2 POLE, 3 POS, NON-SHORTING | 272-007 | | | | | | | | | | | | | | | |
| T1 T2 T3 T4 T5 | TRANSFORMER, I. F. 10.7 MC TRANSFORMER, I.F. 456 KC TRANSFORMER, I.F. 456 KC TRANSFORMER, MODULATION & AUDIO OUTPUT TRANSFORMER, POWER #3019 | 602-002 602-001 602-001 604-004 601-011 | | | | | | | | | | | | | | | |
| V1 V2 V3 V4 V5 V6 V7 V8 V9 V10 V11 V12 V13 | TUBE, ELECTRON, TYPE 6EH7 TUBE, ELECTRON, TYPE 6DJ8 TUBE, ELECTRON, TYPE 6BA6 TUBE, ELECTRON, TYPE 6BA6 TUBE, ELECTRON, TYPE 6BA6 TUBE, ELECTRON, TYPE 12AL5 TUBE, ELECTRON, TYPE 12AL7 TUBE, ELECTRON, TYPE 12AX7 TUBE, ELECTRON, TYPE 6AQ5 TUBE, ELECTRON, TYPE 6AQ5 TUBE, ELECTRON, TYPE 6ER8 TUBE, ELECTRON, TYPE 6KE8 TUBE, ELECTRON, TYPE 6KE8 TUBE, ELECTRON, TYPE 12BY7 TUBE, ELECTRON, TYPE 12BY7 | 216-023 216-021 216-009 216-010 216-009 211-001 211-003 216-006 216-006 216-036 211-011 212-001 | | | | | | | | | | | | | | | |

66'ER ALIGNMENT PROCEDURE

I Front End & I. F. Alignment:

A. Front End Alignment

Equipment: Sweep generator Jerrold #601 or equivalant, production scope - or equivalant, signal generator, H.P. 608 or equivalant.

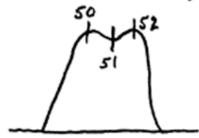
 Connect Jerrold Sweeper (via coax.) to 66'er antenna connector and set Jerrold to:

> Freq. - 15-65 MC. Sweep Width - 3 Center Freq. - 5-9 ALC - 50% Attenuator - 20 db in

- Connect HP 608 (via coax.) to antenna connector through a 1PF capacitor. This is being used as a marker.
- 3. Disconnect VLO B+ (at load end R-74 22K 2W)
- Connect AC coupled scope (via coax.) to pin 3 of V-2 and set scope to:

External Sync. Vertical Att. to 2V. (Full Scale) Sync. in via coax. from Jerrold

- Turn on 66'er. Using 608 as a marker adjust Jerrold center freq. to center scope display at 51 mc. Increase 608 output as necessary to provide visible marker.
- 6. a) Adjust L2 and L3 to center response on 51MC marker.



b) Check response width with marker at 50 & 52 mc. Response should be as shown. c) If too wide, cut off "gimmick" on L3 a little at a time, readjusting L2 & L3 as necessary to obtain response shown. 50 & 52 must be down less than 1 db.

B. I.F. Alignment

Equipment: Signal generator H.P. #608 or equivalent, VTVM RCA #WV77E or equivalent, short clip lead (3").

- 1. Connect HP 608 to antenna connector (via coax.) and set freq. to 10.7 mc unmodulated
- 2. Connect VTVM (-5v scale) to junction R-33, C 35 (AGC Buss).
- 3. Short antenna connector to pin 2 V2 via clip lead.
- a) Increase 608 output until AGC voltage reaches -lv.
 - b) Adjust L4, L5, T1, T2 and T3 for maximum AGC voltage.
 - c) Reduce 608 output as necessary to maintain 1v.
 - d) Repeat step b until there is no change.

II Transmitter Alignment & VLO Tracking

A. Transmitter Alignment

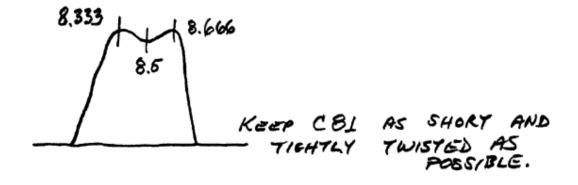
Equipment: Monitor scope

8 mc sweep generator (with 8.333, 8.5 and 8.666 xtal markers)
Dummy Load/watt meter

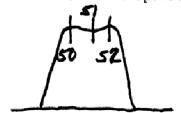
13 V.D.C. Supply Production scope

Shorting mic. plug

- 1. Remove B+ from final amp. v13 (2E26).
- Connect sweep output to xtal socket of 66'er.
- Connect scope vert to junction R77, C83 (cold side of L-10).
- 4. Insert shorting plug in mic socket.
- Adjust L9, C81 and L10 for response shown.



- 6. Move scope probe to junction \$82, C88.
- 7. Connect A jumper across C92.
- 8. Set L11 & L 12 for response shown.



11. Remove probe and sweep connections.

B. Neutralization & Power output Kemove 3+ from 13

- 1. Connect RF detector to antenna connector.
- 2. Insert 8.666 mc. xtal and tune xmtr for max. R.F. output indication.
- 3. Neutralize by clipping "CN" until indication is at minimum.
- 4. Disconnect RF meter and connect Dummy load/wattmeter.
- Replace B+ connection to V13.
- 6. With 8.66 mc. xtal. tune for max. and record on test data sheet.
- 7. Insert 8.33 mc xtal and tune for max. output 10 watts.
- 8. Insert 8.500 mc xtal and tune for max. output 10 watts.
- 9. Plug in mic and check modulation on wattmeter & monitor.
- 10. Replace AC cord with DC cord connected to 13 vdc supply.
- 11. Repeat step 6 above. Min 8 watts.

III Final Test

A. Calibration

Equipment: HP 608

Speaker/Audio VTVM
Dummy Load/Wattmeter

Xtals 8.333, 8.500, 8.666 mc.

- 1. Connect VLO B+.
- Set dial pointer at left marker. Check VLO tuning-capacitor (C-61) at max. (full mesh).
- Set C-15 & C-2 at half way points.

Page four

- Connect HP-608 (via. coax.) to antenna connector. Set HP-608 to 51 mc.
 (30% 1KC 50 UV).
- Set 66'er dial to 51 mc. Tune L-8 & C-15 for max. Signal on audio VTVM connected across speaker leads.
- Reduce HP-608 output to .5 uv. Check still audible. Then reduce HP-608 output to zero.
- 7. Insert 8.333 mc. xtal and set 66'er to spot.
- 8. Set dial to 50 mc. and tune L-8 for max. output. (s-Meter)
- Insert 8.666 mc. xtal. and set dial to 52 mc. Adjust C-62 for max. output.
- Repeat steps 8 & 9 until 50 & 52 mc. are on calibration.

B. Squelch (0.5 uv 1 kc, 30%)

 Set HP-608 & dial to 51 mc. Reduce HP-608 output to zero. Advance squelch (CCW) until just past threshold of quieting. Increase HP-608 output. Squelch must break before .5 uw of output.

C. ANTL

- 1. Set HP-608 to 2 uv (30% 1KC 51 mc.)
- 2. Turn on noise generator and loosely couple into antenna circuit.
- 3. Turn ANL on Noise should disappear from signal.

D. Sensitivity

- Set HP-608 to __.6 uv. (30% 1 Kc 51 mc.).
- Establish 0 db audio output reference with receiver audio.
- Remove mod and record drop in audio output. (db) Drop must be at least 10 db at any point in the band.
- Set S-meter so S-9 = 50-u-v.

E. Audio output

 Set HP-608 to 3 uv (30% 1KC 51 Mc.). Advance receiver audio until onset of audible distortion. At least 2.5 vac should be obtained.

